

LOW VF SCHOTTKY BARRIER RECTIFIERS

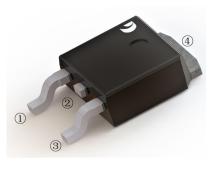
SL2045DS

REVERSE VOLTAGE - 45 Volts FORWARD CURRENT - 20.0 Amperes

FEATURES

- Low power loss, high efficiency
- Low forward voltage drop
- High surge capability
- High temperature soldering guaranteed
- Mounting position: any

<u>TO-252(D-PAK)</u>





MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 $^\circ\!\!\!\!^\circ C$ ambient temperature unless otherwise specified.

PARAMETER	SYMBOL	VALUE	UNIT	
Maximum repetitive peak reverse voltage		Vrrm	45	V
Maximum rms voltage		VRMS	31.5	V
Maximum average forward rectified current		l F(AV)	20	А
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load		I FSM	150	А
Typical junction capacitance (VR=4V, f=1MHz)		CJ	620	pF
Typical thermal resistance per diode (Note	e 1)	Røjc	45	°C/W
Operating junction temperature range		TJ	-55 to + 150	°C
Storage temperature range		Тѕтс	-55 to + 150	°C

Note : 1. Mounted on infinite heatsink.

ELECTRICAL CHARACTERISTICS(TA=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDI	TIONS	MIN.	TYP.	MAX.	UNIT
Breakdown voltage per diode	Vbr	I R=0.5mA		45	-	-	V
Instantaneous forward voltage per diode	VF	F=2A F=5A F=20A F=2A	TJ=25°C	-	0.38 0.42 0.54 0.31	- 0.60 -	V
		I F=5A I F=20A	TJ=125°C	-	0.37 0.48	-	V
Deverse surrent per diade		VR=36V		-	5	-	μΑ
Reverse current per diode	l r	Vr=45V	TJ=25°C TJ=125°C	-	- 9.5	50 -	μA mA



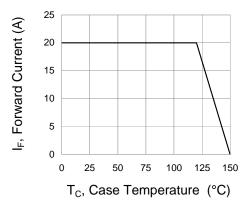


Fig.1 Forward Current Derating Curve

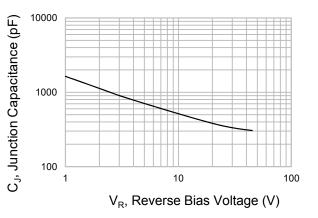
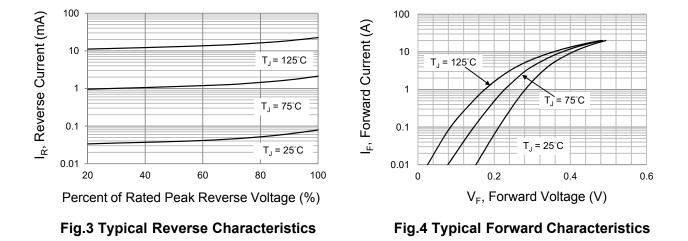
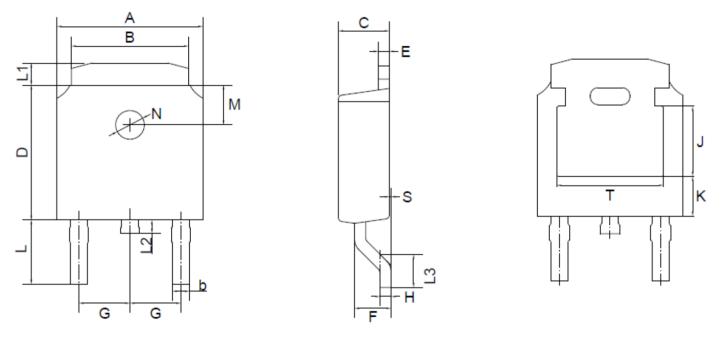


Fig.2 Typical Junction Capacitance









TO-252(D-PAK) mechanical data

UN	IT	Α	В	b	С	D	Е	F	G	н	L	L1	L2	L3	S	М	N	J	к	т
	max	6.7	5.5	0.8	2.5	6.3	0.6	1.8	2.29	0.55	3.1	1.2	1.0	1.75	0.1	1.8	1.3	3.16	1.80	4.83
mm	min	6.3	5.1	0.3	2.1	5.9	0.4	1.3	TYPICAL	0.45	2.7	<mark>0.8</mark>	0.6	1.40	0.0	TYPICAL	TYPICAL	ref.	ref.	ref.
mil	max	264	217	31	98	248	24	71	90	22	122	47	39	69	4	71	51	124	71	190
	min	248	201	12	83	232	16	51	TYPICAL	18	106	31	24	55	0	TYPICAL	TYPICAL	ref.	ref.	ref.

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